

STTH6006TV

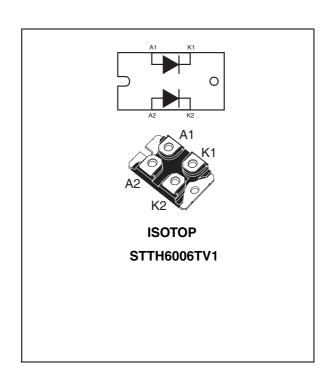
Turbo 2 ultrafast - high voltage rectifier

Main product characteristics

I _{F(AV)}	2 x 30 A
V _{RRM}	600 V
Tj	150° C
V _F (typ)	1.1 V
t _{rr} (max)	50 ns

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces conduction and switching losses
- Insulated voltage: 2500 V_{RMS}
- Typical package capacitance: 45 pF



Description

The STTH6006TV1 uses ST Turbo2 600V technology. This device is specially suited for use in switching power supplies, and industrial applications such as rectification and PFC boost diode.

Order codes

Part Number	Marking		
STTH6006TV1	STTH6006TV1		

Table 1. Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			600	V
I _{F(RMS)}	RMS forward current			100	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$	Per diode	T _c = 70° C	30	Α
I _{FSM}	Surge non repetitive forward current t _p = 10 ms Sinusoidal		210	Α	
T _{stg}	Storage temperature range			-55 to + 150	°C
T _j	Maximum operating junction temperature ⁽¹⁾			150	°C

^{1.} $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

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Table 2. Thermal parameters

Symbol	Parameter		Value	Unit
P	Junction to case	Per diode	1.6	
$R_{th(j-c)}$	Junction to case	Total	0.85	° C/W
R _{th(c)}	Coupling	•	0.1	

When the diodes are used simultaneously:

 $\Delta T_{j(diode1)} = P_{(diode1)} \times R_{th(j-c)}$ (per diode) + $P_{(diode2)} \times R_{th(c)}$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Povorco logizado current	T _j = 25° C	V _R = V _{RRM}			25	μA
'R`	I _R ⁽¹⁾ Reverse leakage current	T _j = 125° C			80	800	μΑ
V _E (2)	V _E ⁽²⁾ Forward voltage drop		I _F = 30 A			1.85	٧
VF`	v _F , / Forward voltage drop	T _j = 150° C	IF = 30 A		1.10	1.40	V

- 1. Pulse test: $t_p = 5$ ms, $\delta < 2$ %
- 2. Pulse test: $t_p = 380 \mu s$, $\delta < 2 \%$

To evaluate the conduction losses use the following equation:

 $P = 1.07 \times I_{F(AV)} + 0.011 I_{F}^{2}_{(RMS)}$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
t _{rr} Reverse recovery time		$I_F = 0.5 \text{ A}, I_{rr} = 0.25 \text{ A}, I_R = 1 \text{ A},$ $T_j = 25^{\circ} \text{ C}$			50	ns
		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		50	70	115
I _{RM}	Reverse recovery current	$I_F = 30 \text{ A}, dI_F/dt = -100 \text{ A/}\mu\text{s}, \ V_R = 400 \text{ V}, T_j = 125^{\circ} \text{ C}$		8	11	
t _{fr}	Forward recovery time	$I_F = 30 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$			500	ns
V _{FP}	Forward recovery voltage	$I_F = 30 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$		2.5		V

STTH6006TV Characteristics

Figure 1. Conduction losses versus average current

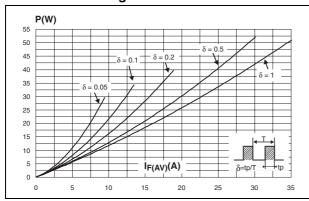


Figure 2. Forward voltage drop versus forward current

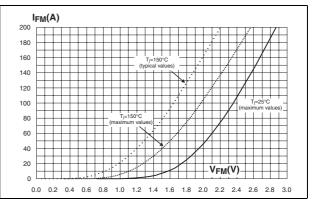


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Zth(j-c)/Rth(j-c)

1.0

0.9

Single pulse

0.7

0.6

0.5

0.4

0.3

0.2

0.1

0.0

1.E-03

1.E-02

1.E-01

1.E+00

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)

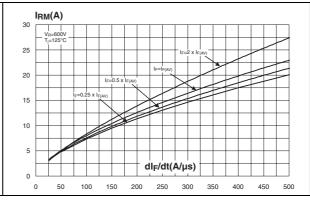


Figure 5. Reverse recovery time versus dl_F/dt (typical values)

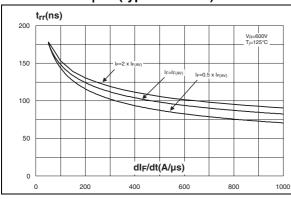
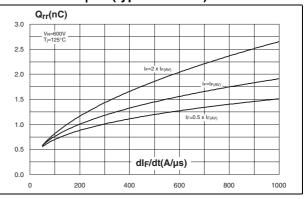


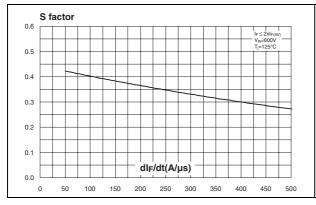
Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



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Figure 7. Softness factor versus dl_F/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature



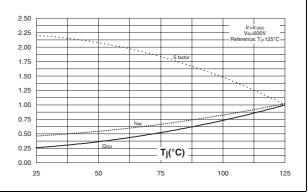
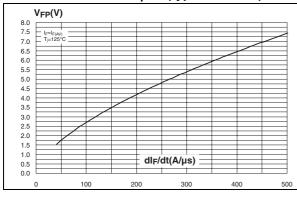


Figure 9. Transient peak forward voltage versus dl_E/dt (typical values)

Figure 10. Forward recovery time versus dl_F/dt (typical values)



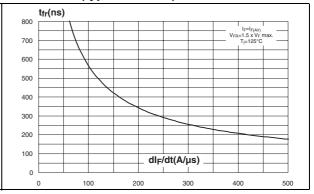
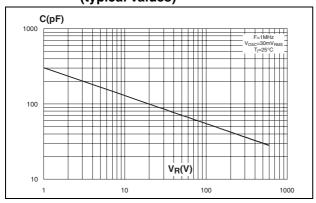


Figure 11. Junction capacitance versus reverse voltage applied (typical values)

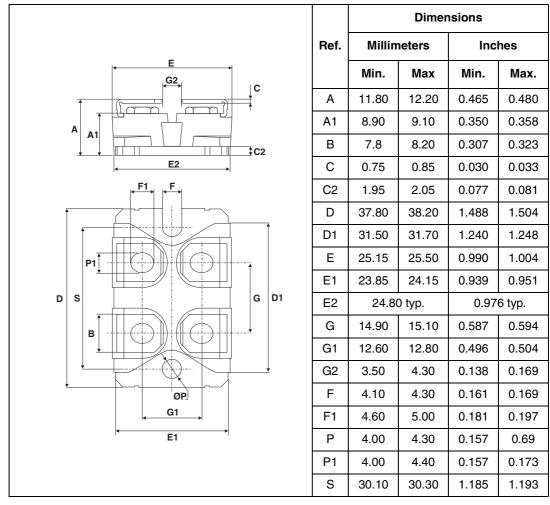


2 Package mechanical data

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Table 5. ISOTOP dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Ordering information STTH6006TV

3 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH6006TV1	STTH6006TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

Date	Revision	Description of Changes
18-May-2006	1	First issue.

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